

RF AMPLIFIER

MODEL *TM3026*

Available as: TM3026, 4 Pin TO-8 (T4)
 TN3026, 4 Pin Surface Mount (SM3)
 FP3026, 4 Pin Flatpack (FP4)
 BX3026, Connectorized Housing (H1)

Features

- High Output Power: +28 dBm Typical
- High Third Order Intercept: +40 dBm Typical
- Operating Temp. -55 °C to + 85 °C
- Environmental Screening Available

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency	50 - 160 MHz	50 - 160 MHz
Gain (dB)	14.5	12.0 Min.
Power @ 1 dB Comp. (dBm)	+28	+27 Min.
Reverse Isolation (dB)	-17.5	-16
VSWR In	<1.5:1	2.0:1 Max.
Out	<1.5:1	2.0:1 Max.
Noise Figure (dB)	<5.0	6.0 Max.
Power Vdc	+24	+24 Min.
mA	170	180 Max.

Note: Care should always be taken to effectively ground the case of each unit.

Typical Intermodulation Performance at 25 ° C

Second Order Harmonic Intercept Point +50 dBm (Typ.)
 Second Order Two Tone Intercept Point +48 dBm (Typ.)
 Third Order Two Tone Intercept Point +40 dBm (Typ.)

Maximum Ratings

Ambient Operating Temperature -55°C to + 100 °C
 Storage Temperature -62°C to + 125 °C
 Case Temperature + 125 °C
 DC Voltage + 28 Volts
 Continuous RF Input Power + 18 dBm
 Short Term RF Input Power 100 Milliwatts (1 Minute Max.)
 Maximum Peak Power 0.5 Watt (3 µsec Max.)

Typical Performance Data

